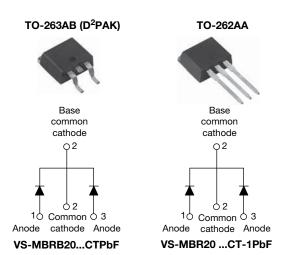


www.vishay.com

Vishay Semiconductors

# High Performance Schottky Rectifier, 2 x 10 A



PRODUCT SUMMARY	
Package	TO-263AB (D <sup>2</sup> PAK), TO-262AA
$I_{F(AV)}$	2 x 10 A
$V_{R}$	80 V, 90 V, 100 V
V <sub>F</sub> at I <sub>F</sub>	0.70 V
I <sub>RM</sub> max.	15 mA at 125 °C
$T_J$ max.	150 °C
Diode variation	Common cathode
E <sub>AS</sub>	8.0 mJ

## **FEATURES**

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High frequency operation
- Center tap D<sup>2</sup>PAK and TO-262 packages
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **DESCRIPTION**

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I <sub>F(AV)</sub>	Rectangular waveform (per device)	20	A		
I <sub>FRM</sub>	T <sub>C</sub> = 133 °C (per leg)	20	A		
$V_{RRM}$		80 to 100	V		
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	850	Α		
V <sub>F</sub>	10 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.70	V		
$T_J$	Range	-65 to +150	°C		

VOLTAGE RATINGS						
PARAMETER SYMBOL VS-MBRB2080CTPbF VS-MBRB2090CTPbF VS-MBRB20100CTPbF VS-MBR2090CT-1PbF VS-MBR2090CT-1PbF VS-MBR20100CT-1PbF VS-MBR2090CT-1PbF VS-MBR20100CT-1PbF VS-M						
Maximum DC reverse voltage	$V_R$	80	90	100	V	
Maximum working peak reverse voltage	$V_{RWM}$	80	90	100	V	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	BOL TEST CONDITIONS		UNITS	
Maximum average per leg	1	L T 100 °C			
forward current per device	I <sub>F(AV)</sub>	T <sub>C</sub> = 133 °C, rated V <sub>R</sub>	20		
Peak repetitive forward current per leg	per leg I <sub>FRM</sub> Rated V <sub>R</sub> , square wave, 20 kHz, T <sub>C</sub> = 133 °C		20		
Non-repetitive peak surge current	1	5 μs sine or 3 μs rect. pulse Following any rated load condition and with rated V <sub>RRM</sub> applied	850	А	
Non-repetitive peak surge current	IFSM	Surge applied at rated load conditions half wave, single phase, 60 Hz	150		
Peak repetitive reverse surge current	I <sub>RRM</sub>	2.0 μs, 1.0 kHz	0.5		
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	$T_J = 25  ^{\circ}\text{C},  I_{AS} = 2  \text{A},  L = 12  \text{mH}$	24	mJ	

Revision: 18-Oct-16 1 Document Number: 94306



www.vishay.com

# Vishay Semiconductors

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
		10 A	T <sub>.1</sub> = 25 °C	0.80	V
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	20 A	1J=25 C	0.95	
Maximum forward voltage drop	VFM (')	10 A	T 105 °C	0.70	
		20 A	- T <sub>J</sub> = 125 °C	0.85	
Maximum instantaneous	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	Rated DC voltage	0.10	- mA
reverse current		T <sub>J</sub> = 125 °C	hated DC voltage	6	
Threshold voltage	V <sub>F(TO)</sub>	T - T movimum		0.433	V
Forward slope resistance	r <sub>t</sub>	$T_J = T_J$ maximum		15.8	mΩ
Maximum junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 5 V <sub>DC</sub> (test signal ran	ge 100 kHz to 1 MHz), 25 °C	400	pF
Typical series inductance	L <sub>S</sub>	Measured from top of terminal to mounting plane		8.0	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs

## Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECH	THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction tempera	Maximum junction temperature range			-65 to +150	°C	
Maximum storage tempera	ture range	$T_{Stg}$		-65 to +175	-0	
Maximum thermal resistance, junction to case per leg		R <sub>thJC</sub>	DC operation	2.0		
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50	°C/W	
Maximum thermal resistance, junction to ambient		$R_{thJA}$	DC operation	50		
Approximate weight				2	g	
Approximate weight				0.07	OZ.	
minimum			Non-lubricated threads	6 (5)	kgf · cm	
Mounting torque maxin	maximum		Non-lubricated tilleads	12 (10)	(lbf · in)	
Marking davise	Madding daying		Case style D <sup>2</sup> PAK	MBRB2	0100CT	
Marking device			Case style TO-262	MBR20	100CT-1	





www.vishay.com

# Vishay Semiconductors

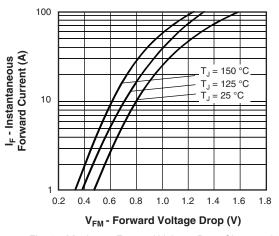


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

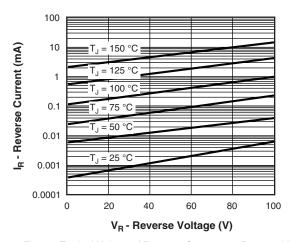


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

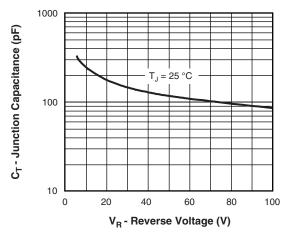


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

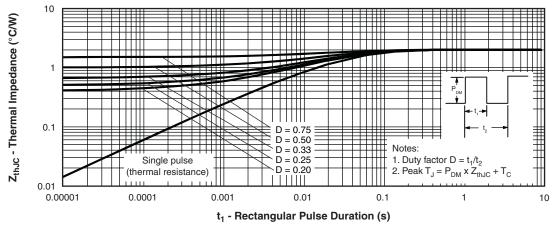


Fig. 4 - Maximum Thermal Impedance  $Z_{\text{thJC}}$  Characteristics (Per Leg)



www.vishay.com

Vishay Semiconductors

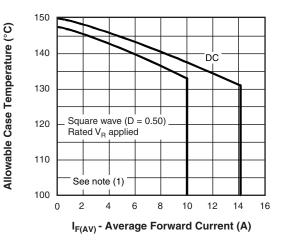


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

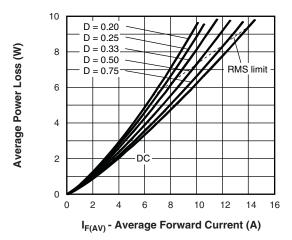


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

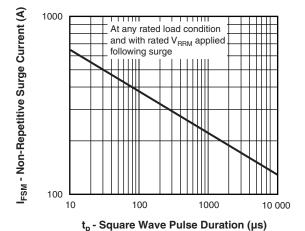


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

## Note

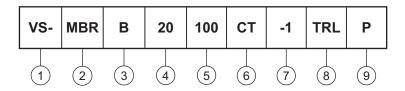
(1) Formula used: T<sub>C</sub> = T<sub>J</sub> - (Pd + Pd<sub>REV</sub>) x R<sub>th,JC</sub>; Pd = forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 6); Pd<sub>REV</sub> = inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = rated V<sub>R</sub>



Vishay Semiconductors

## **ORDERING INFORMATION TABLE**

**Device code** 



- 1 Vishay Semiconductors product
- 2 Essential part number
- B = D<sup>2</sup>PAK
   None = TO-262
  7 = -1
- Current rating (20 = 20 A) 80 = 80 V 5 - Voltage ratings 90 = 90 V
- 5 Voltage ratings 90 = 90 V 6 - CT = essential part number
- 7 • None = D<sup>2</sup>PAK 3 = B • -1 = TO-262 3 None 8 - • None = tube (50 pieces)
- None = tube (50 pieces)
  TRL = tape and reel (left oriented for D<sup>2</sup>PAK only)
  - TRR = tape and reel (right oriented for D<sup>2</sup>PAK only)
- 9 • PbF = lead (Pb)-free (for TO-262 and D<sup>2</sup>PAK tube)
  - P = lead (Pb)-free (for D<sup>2</sup>PAK TRR and TRL)

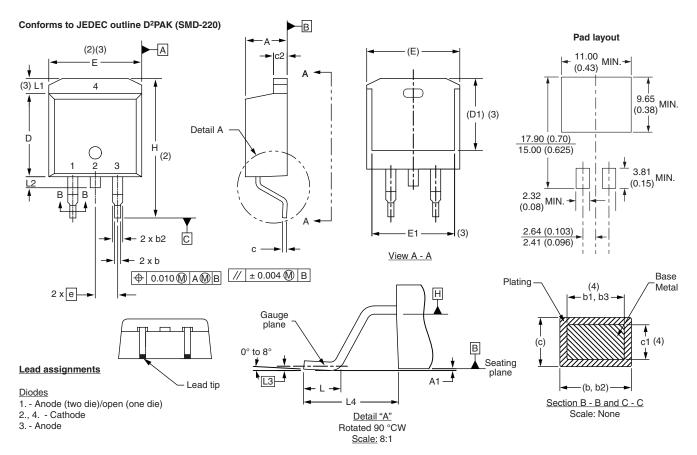
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95014			
Part marking information	www.vishay.com/doc?95008			
Packaging information	www.vishay.com/doc?95032			



## Vishay Semiconductors

# **D<sup>2</sup>PAK, TO-262**

## **DIMENSIONS - D<sup>2</sup>PAK** in millimeters and inches



	1		1		t .
SYMBOL	MILLIN	IETERS	INC	NOTES	
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25	BSC	0.010	BSC	
L4	4.78	5.28	0.188	0.208	

#### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$  Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch

(7) Outline conforms to JEDEC outline TO-263AB

Document Number: 95014 Revision: 31-Mar-09

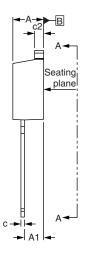
# Vishay Semiconductors

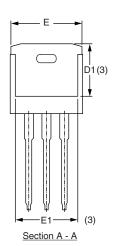
D<sup>2</sup>PAK, TO-262



## **DIMENSIONS - TO-262** in millimeters and inches

# 





**⊕** 0.010 **M** A **M** B

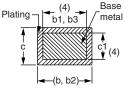
#### Lead assignments



#### **Diodes**

1. - Anode (two die)/open (one die) 2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

SYMBOL	MILLIM	MILLIMETERS		INCHES		
	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
Е	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54 BSC		0.100	D BSC		
L	13.46	14.10	0.530	0.555		
L1	=	1.65	-	0.065	3	
L2	3.56	3.71	0.140	0.146		

## Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline

# **Legal Disclaimer Notice**



Vishay

## **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2017 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED